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This listing of claims will replace all prior versions of claims in the application.

Claims 1-44. (cancelled)

- Claim 45. (currently amended) A chemically-amplified positive-acting photoresist composition comprising:
 - a) a resin that comprises photoacid-labile groups; and
- b) one or more photoacid generator compounds other than a N-oxyimidosulfonate that upon exposure to activating radiation generate an acid of the formula R(CR¹R2)CF₂SO₃H where R is optionally substituted alkyl having 4 to about 20 carbon atoms, optionally substituted alicyclic group, optionally substituted carbocyclic aryl group, optionally substituted heteroalicyclic group, or optionally substituted heteroaromatic group, and R is not perhaloalkyl; and
 - R¹ and R² are each independently hydrogen or non-hydrogen substituent,
- Claim 46. (previously presented) The photoresist composition of claim 45 wherein R is optionally substituted alkyl.
- Claim 47. (previously presented) The photoresist composition of claim 45 wherein R is an optionally substituted alicyclic group.
- Claim 48. (previously presented) The photoresist composition of claim 45 wherein R is an optionally substituted carbocyclic aryl group.
- Claim 49. (previously presented) The photoresist composition of claim 45 wherein R is an optionally substituted heteroalicyclic group, or optionally substituted heteroaromatic group.

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- Claim 50. (previously presented) The photoresist composition of claim 45 wherein the one or more photoacid generator compounds are iodonium compounds.
- Claim 51. (previously presented) The photoresist composition of claim 45 wherein the one or more photoacid generator compounds are sulfonium compounds.
- Claim 52. (previously presented) The photoresist of claim 45 wherein the one or more photoacid generators are non-ionic compounds.
- Claim 53. (currently amended) The photoresist composition of claim 45 52 wherein the one or more photoacid generator compounds are sulfonate compounds.
 - Claim 54. (cancelled)
- Claim 55. (currently amended) The photoresist composition of claim 45 wherein the one or more photoacid generator compounds are diazosulfone compounds.
- Claim 56. (previously presented) The photoresist composition of claim 45 wherein the resin comprises phenolic groups.
- Claim 57. (previously presented) The photoresist composition of claim 45 wherein the resin is at least substantially free of aromatic groups.
- Claim 58. (previously presented) The photoresist of claim 45 wherein the resin is completely free of aromatic groups.
- Claim 59. (previously presented) An article of manufacture comprising a coating layer of a photoresist composition of claim 45.

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Claim 60. (previously presented) The article of manufacture of claim 59 wherein the article is a microelectronic wafer substrate.